OSRAM LE D P2MQ **Datasheet**

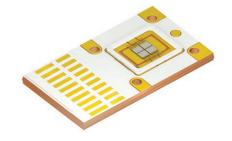




OSRAM OSTAR™ Projection Power

LE D P2MQ

OSRAM OSTAR Projection Power is a high luminance LED for projection applications.







Applications

- Projection & Display

- Visualization

Features

- Package: OSTAR High Power Projection

- Chip technology: UX:3

- Typ. Radiation: 120° (Lambertian emitter)

- Color: λ_{dom} = 440 nm (• deep blue)

- ESD: 2 kV acc. to ANSI/ESDA/JEDEC JS-001 (HBM, Class 2)

Ordering Information

Total radiant flux 1) Type Ordering Code $I_{r} = 10000 \text{ mA}$

LE D P2MQ-JQJT-R 48400 ... 65800 mW Q65115A0642



Maximum Ratings			
Parameter	Symbol		Values
Storage Temperature	T_{stg}	min. max.	-40 °C 85 °C
Junction Temperature	T _j	max.	150 °C
Forward Current $T_{j} = T_{j,max}$	I _F	min. max.	200 mA 10000 mA
Forward Current pulsed $D = 0.7$; $f = 240 \text{ Hz}$; $T_j = T_{j,max}$	F pulse		12000 mA
Surge Current $t_P \le 50 \ \mu s; \ D = 0.1; \ T_j = T_{j,max}$	I _{FS}	max.	14000 mA
ESD withstand voltage acc. to ANSI/ESDA/JEDEC JS-001 (HBM, Class 2)	V_{ESD}		2 kV
Reverse current 2)	I _R	max.	200 mA
Max. voltage difference anode-board, cathode-board	ΔV_{a-b} , ΔV_{c-b}	max.	40 V



Characteristics

 $I_F = 10000 \text{ mA}; T_B = 25 \text{ °C}$

Parameter	Symbol		Values
Peak Wavelength	λ_{peak}	typ.	430 nm
Dominant Wavelength 3)	$\lambda_{\sf dom}$	min.	435 nm
	33	typ.	440 nm
		max.	445 nm
Spectral bandwidth at 50% I _{rel,max}	Δλ	typ.	20 nm
Viewing angle at 50% $\rm I_{\rm v}$	2φ	typ.	120 °
Radiating surface	A_{color}	typ.	3.2 x 2.6 mm ²
Partial Flux acc. CIE 127:2007 4)	Φ _{E/V, 120°}	typ.	0.77
$I_F = 10000 \text{ mA}$			
Forward Voltage 5)	V _F	min.	14.0 V
$I_{\rm F} = 10000 \text{mA}$	·	typ.	16.0 V
		max.	18.0 V
Reverse voltage (ESD device)	$V_{_{ m RESD}}$	min.	45 V
Reverse voltage ²⁾	V_{R}	max.	1.2 V
I _R = 20 mA			
Real thermal resistance junction/board	$R_{ ext{thJB real}}$	typ.	0.7 K / W
Electrical thermal resistance junction/board	$R_{ ext{thJB elec.}}$	typ.	0.46 K / W
with efficiency η_e = 34 %			



Brightness Groups

Group	Total radiant flux $^{1)}$ I _F = 10000 mA min. Φ_{e}	Total radiant flux $^{1)}$ I _F = 10000 mA max. $\Phi_{\rm e}$
JQ	48400 mW	52000 mW
JR	52000 mW	56300 mW
JS	56300 mW	61000 mW
JT	61000 mW	65800 mW

Wavelength Groups

Group	Dominant Wavelength 3)	Dominant Wavelength 3)	
	min.	max.	
	$\lambda_{\sf dom}$	$\lambda_{\sf dom}$	
R	435 nm	445 nm	

Group Name on Label

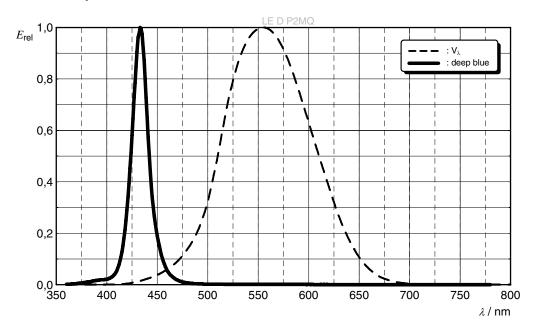
Example: JQ-R

Brightness	Wavelength
JQ	R



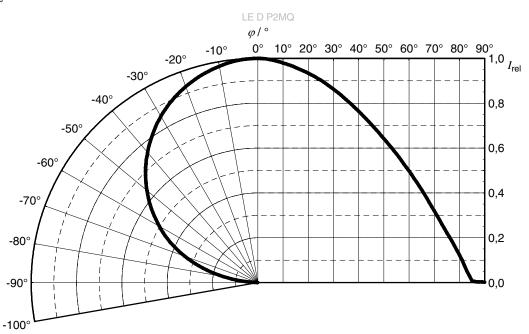
Relative Spectral Emission 4)

 E_{rel} = f (λ); I_F = 10000 mA; T_J = 25 °C



Radiation Characteristics 4)

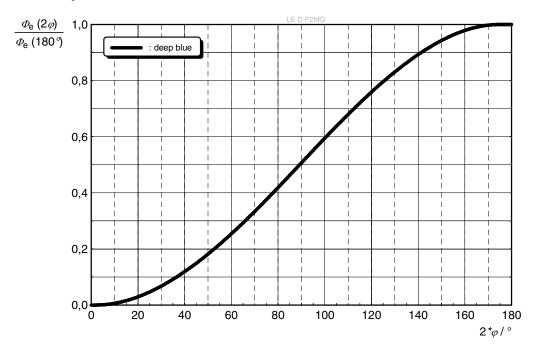
 $I_{rel} = f(\phi); T_J = 25 \, ^{\circ}C$





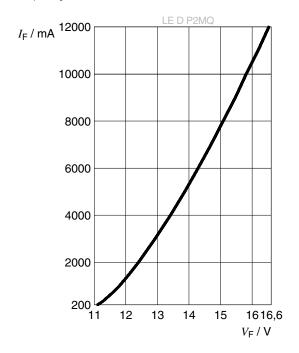
Relative Partial Flux 4)

 $\Phi_{\scriptscriptstyle E}(2\phi)/\Phi_{\scriptscriptstyle E}(180^\circ)$ = f(ϕ); T_J = 25 °C



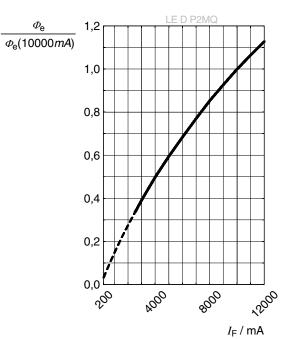
Forward current 4)

$$I_F = f(V_F); T_J = 25 °C$$



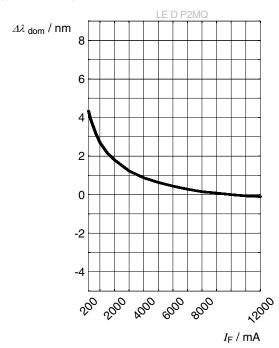
Relative Radiant Power 4), 6)

$$\Phi_{\rm E}/\Phi_{\rm E}(10000 \text{ mA}) = f(I_{\rm E}); T_{\rm J} = 25 \,^{\circ}\text{C}$$



Dominant Wavelength 4)

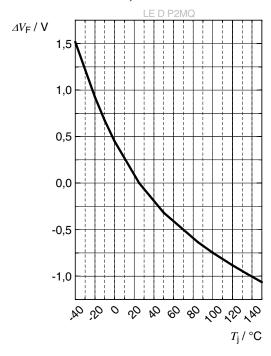
$$\Delta\lambda_{dom} = f(I_F); T_J = 25 \text{ }^{\circ}\text{C}$$





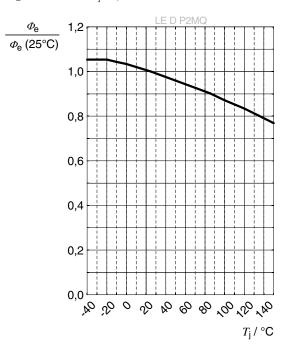
Forward Voltage 4)

$$\Delta V_{_F} = V_{_F} - V_{_F} (25~^{\circ}C) = f(T_{_j}); I_{_F} = 10000~mA$$



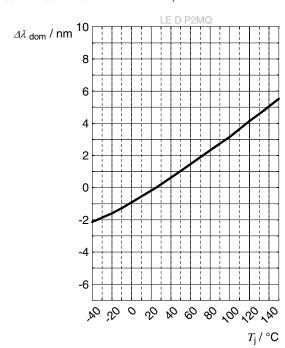
Relative Radiant Power 4)

$$\Phi_{\rm E}/\Phi_{\rm E}(25~{\rm ^{\circ}C}) = f(T_{\rm i}); I_{\rm E} = 10000~{\rm mA}$$



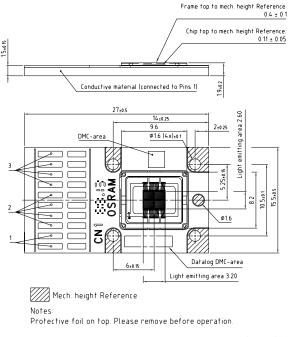
Dominant Wavelength 4)

$$\Delta \lambda_{dom} = \lambda_{dom} - \lambda_{dom} (25 \ ^{\circ}C) = f(T_{j}); I_{F} = 10000 \ mA$$





Dimensional Drawing 7)



C63062-A4390-A1-05

Molex Pico-SPOX™ Wire-to-Board Housing, Part Number 87439-1000

Further Information:

Approximate Weight: 5,000.0 mg

ESD advice: The device is protected by ESD device which is connected in parallel to the

Chip.

Notes: Package not suitable for any kind of wet cleaning or ultrasonic cleaning.

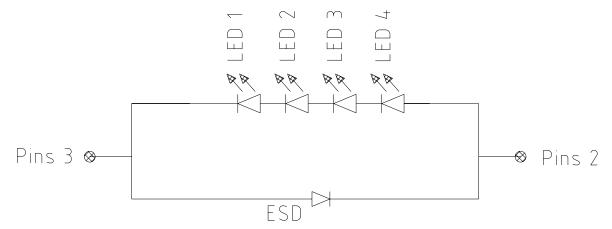
Connector: Molex Pico-SPOX™ Wire-to-Board Header, Part Number 87438-1043

Recommended mating

connector: Crimp Terminal, Part Number 87421-0000



Electrical Internal Circuit



Pins 1: Substrate potential, isolated from Cathode and Anode

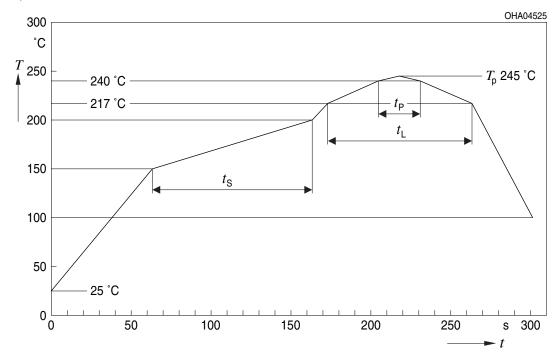
Pins 2: Anode

Pins 3: Cathode



Reflow Soldering Profile

Product complies to MSL Level 2 acc. to JEDEC J-STD-020E



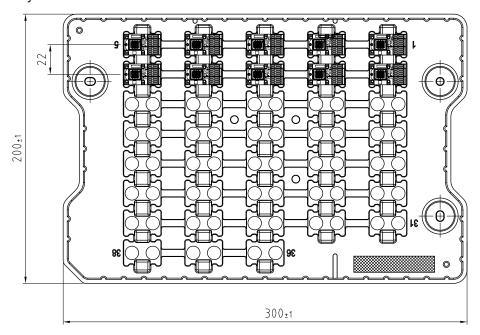
Profile Feature	Symbol	Pb	Pb-Free (SnAgCu) Assembly		
		Minimum	Recommendation	Maximum	
Ramp-up rate to preheat*)			2	3	K/s
25 °C to 150 °C					
Time t _s	t_s	60	100	120	S
T_{Smin} to T_{Smax}					
Ramp-up rate to peak*)			2	3	K/s
T_{Smax} to T_{P}					
Liquidus temperature	T_{L}		217		°C
Time above liquidus temperature	$t_{\scriptscriptstyle \perp}$		80	100	S
Peak temperature	T_{P}		245	260	°C
Time within 5 °C of the specified peak temperature T _p - 5 K	t _P	10	20	30	S
Ramp-down rate* T _p to 100 °C			3	6	K/s
Time 25 °C to T _P				480	S

All temperatures refer to the center of the package, measured on the top of the component

^{*} slope calculation DT/Dt: Dt max. 5 s; fulfillment for the whole T-range



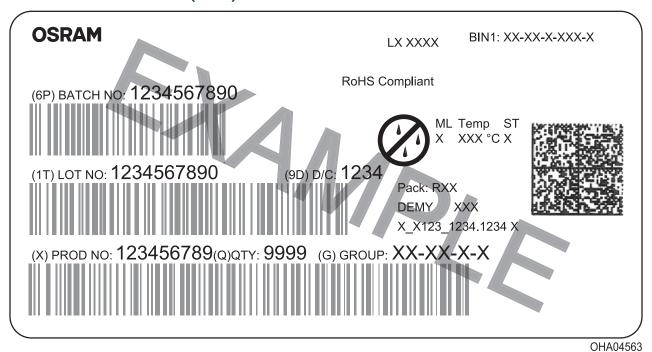
Tray 7) 38 pieces per tray



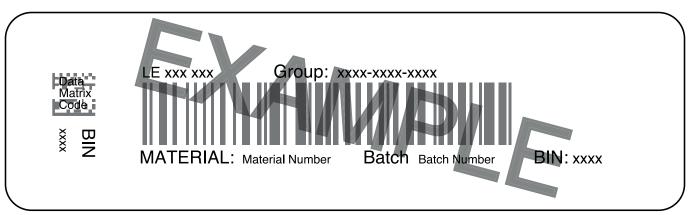
C63062-A4389-B10-01



Barcode-Product-Label (BPL)



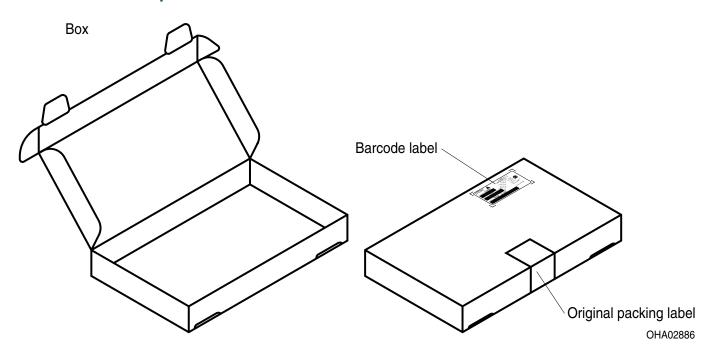
Barcode-Tray-Label (BTL)



OHA02684_1



Schematic Transportation Box 7)



Dimensions of Transportation Box

Width	Length	Height	
333 ± 5 mm	218 ±5 mm	28 ± 5 mm	
337 ± 5 mm	218 ±5 mm	63 ± 5 mm	



Data Matrix Code Description

The Data Matrix Code bin information is Laser marked during testing

Content: aaaa@bbbb@ccc@ddddd@eeeee

Data Matrix Code Type: ECC200

a = Luminous Flux (Phiv) [lm] or Radiant Flux (Phie) [W]	(example: 3306)
b = Forward Voltage (Vf) [V]	(example: 3.46)
c = Wavelength (Ldom) [nm]	(example: 618)
d = Color Coordinate Cx	(example: 0.321)
e = Color Coordinate Cy	(example: 0.641)

@: Seperator = Blank

LE D P2MQ DATASHEET



Notes

The evaluation of eye safety occurs according to the standard IEC 62471:2006 (photo biological safety of lamps and lamp systems). Within the risk grouping system of this IEC standard, the device specified in this data sheet fall into the class moderate risk (exposure time 0.25 s). Under real circumstances (for exposure time, conditions of the eye pupils, observation distance), it is assumed that no endangerment to the eye exists from these devices. As a matter of principle, however, it should be mentioned that intense light sources have a high secondary exposure potential due to their blinding effect. When looking at bright light sources (e.g. headlights), temporary reduction in visual acuity and afterimages can occur, leading to irritation, annoyance, visual impairment, and even accidents, depending on the situation.

Subcomponents of this device contain, in addition to other substances, metal filled materials including silver. Metal filled materials can be affected by environments that contain traces of aggressive substances. Therefore, we recommend that customers minimize device exposure to aggressive substances during storage, production, and use. Devices that showed visible discoloration when tested using the described tests above did show no performance deviations within failure limits during the stated test duration. Respective failure limits are described in the IEC60810.

For further application related information please visit https://ams-osram.com/support/application-notes



Disclaimer

Attention please!

The information describes the type of component and shall not be considered as assured characteristics. Terms of delivery and rights to change design reserved. Due to technical requirements components may contain dangerous substances.

For information on the types in question please contact our Sales Organization.

If printed or downloaded, please find the latest version on our website.

Packing

Please use the recycling operators known to you. We can also help you – get in touch with your nearest sales office. By agreement we will take packing material back, if it is sorted. You must bear the costs of transport. For packing material that is returned to us unsorted or which we are not obliged to accept, we shall have to invoice you for any costs incurred.

Product and functional safety devices/applications or medical devices/applications

Our components are not developed, constructed or tested for the application as safety relevant component or for the application in medical devices.

Our products are not qualified at module and system level for such application.

In case buyer – or customer supplied by buyer – considers using our components in product safety devices/ applications or medical devices/applications, buyer and/or customer has to inform our local sales partner immediately and we and buyer and /or customer will analyze and coordinate the customer-specific request between us and buyer and/or customer.



Glossary

- Brightness: Brightness values are measured during a current pulse of typically 1 ms, with an internal reproducibility of ±8 % and an expanded uncertainty of ±11 % (acc. to GUM with a coverage factor of k = 3).
- Reverse Operation: This product is intended to be operated applying a forward current within the specified range. Applying any continuous reverse bias or forward bias below the voltage range of light emission shall be avoided because it may cause migration which can change the electro-optical characteristics or damage the LED.
- Wavelength: The wavelength is measured at a current pulse of typically 1 ms, with an internal reproducibility of ±0.5 nm and an expanded uncertainty of ±1 nm (acc. to GUM with a coverage factor of k =
- Typical Values: Due to the special conditions of the manufacturing processes of semiconductor devices, the typical data or calculated correlations of technical parameters can only reflect statistical figures. These do not necessarily correspond to the actual parameters of each single product, which could differ from the typical data and calculated correlations or the typical characteristic line. If requested, e.g. because of technical improvements, these typ. data will be changed without any further notice.
- Forward Voltage: The forward voltage is measured during a current pulse of typically 1 ms, with an internal reproducibility of ±0.05 V and an expanded uncertainty of ±0.1 V (acc. to GUM with a coverage factor of k = 3).
- Characteristic curve: In the range where the line of the graph is broken, you must expect higher differences between single devices within one packing unit.
- Tolerance of Measure: Unless otherwise noted in drawing, tolerances are specified with ±0.1 and dimensions are specified in mm.

1.3

1.4

1.5

2024-04-12

2025-03-10

2025-06-12



Revision History		
Version	Date	Change
1.0	2019-08-16	Initial Version
1.0	2019-09-19	Initial Version
1.1	2020-02-18	Maximum Ratings Characteristics
1.2	2021-06-14	Ordering Information Brightness Groups Characteristics Maximum Ratings Dimensional Drawing

Electro - Optical Characteristics (Diagrams)

Electro - Optical Characteristics (Diagrams)

Ordering Information Brightness Groups Characteristics

Ordering Information Characteristics **Brightness Groups**

Glossary

Brand



EU RoHS and China RoHS compliant product 此产品符合欧盟 RoHS 指令的要求; 按照中国的相关法规和标准, 不含有毒有害物质或元素。

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Tobelbader Strasse 30, 8141 Premstaetten, Austria Phone +43 3136 500-0 ams-osram.com © All rights reserved



